



Attorney Docket SEL 147-CON

2823
#7/ Amdtl
4/24/02

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of)
)
Hisashi OHTANI)
)
Serial No.: 09/916,913)
)
Filed: July 27, 2001)
)
For: Method Of Manufacturing)
Thin Film Transistor)
)
Art Unit: 2823)
)
Examiner: D. Collins)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:
the Commissioner for Patents, Washington, D.C. 20231 on
March 22, 2002
Rachelle Hammerquist
Signature Date 3/22/02

Commissioner for Patents
Washington, D.C. 20231

VOLUNTARY AMENDMENT B

Sir:

Please amend the above-identified application as follows:

IN THE CLAIMS:

Please add the following new claims:

33 (New) An organic electroluminescence display device comprising:

04/25/2002 09:00:01 00000000 001029 09010913
a resin substrate;

01 FC:103 198.00 CH
02 FC:102 520.00 CH

an underlying insulating film formed on the resin substrate; and

a channel region of a thin film transistor formed over the underlying insulating film,

C1 said channel region comprising crystalline silicon,

wherein the underlying insulating film comprises a first insulating film comprising a nitride and a second insulating film comprising silicon oxide.

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